

**Degradation of 600-V 4H-SiC Schottky diodes under irradiation with 0.9 MeV electrons**

Lebedev, Alexander A.; Davidovskaja, Klavdia; Kozlovski, Vitali V.; **Korolkov, Oleg; Sleptšuk, Natalja; Toompuu, Jana** Silicon Carbide and Related Materials 2016 : selected, peer reviewed papers from the 11th European Conference on Silicon Carbide and Related Materials 2016 (ECSCRM 2016), September 25-29, 2016, Halkidiki, Greece 2017 / p. 447-450 : ill  
<https://doi.org/10.4028/www.scientific.net/MSF.897.447>

**Surface structure transformation in double forged tungsten upon single and sequenced irradiation using different types of radiation facilities**

Demina, E. V.; Gribkov, V. A.; Laas, Tõnu; **Shirokova, Veronika** Inorganic materials : applied research 2018 / p. 832–847 : ill  
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